

PROTECTION PRODUCTS

Description

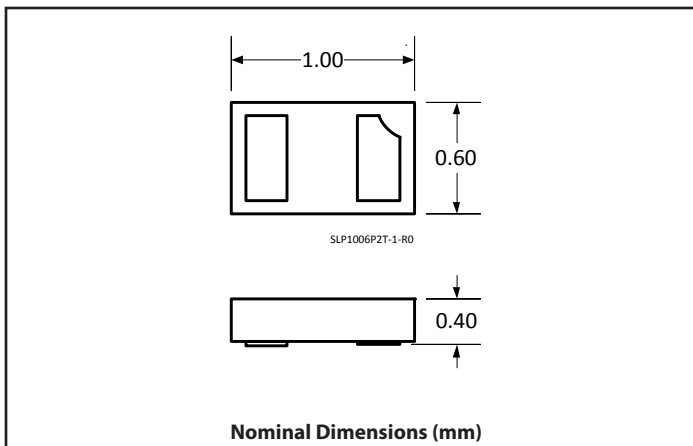
RailClamp is an ultra low capacitance Transient Voltage Suppressor (TVS) designed to protect high speed data interfaces. This device has been specifically designed to protect sensitive components which are connected to high-speed data and transmission lines from overvoltage caused by ESD (electrostatic discharge), CDE (Cable Discharge Events), and EFT (electrical fast transients).

The RClamp™0531TQ has a maximum capacitance of only 0.80pF. This allows it to be used on circuits operating in excess of 2.5GHz without signal attenuation. They may be used to meet the ESD immunity requirements of IEC 61000-4-2.

The RClamp0531TQ is in a 2-pin SLP1006P2T package measuring 1.0 x 0.6 x 0.4mm. The leads are spaced at a pitch of 0.65mm and feature a lead-free finish. Each device will protect one high-speed line operating at 5 volts. It gives the designer the flexibility to protect single lines in applications where arrays are not practical. The combination of small size, low capacitance, and high ESD surge capability makes them ideal for use in applications such as cellular phones and digital video interfaces.

The RClamp0531TQ is AEC-Q100 Grade 1 qualified for Automotive use.

Package Dimension



Features

- Transient protection for data lines to IEC 61000-4-2 (ESD) $\pm 20\text{kV}$ (air), $\pm 12\text{kV}$ (contact)
- IEC 61000-4-4 (EFT) 40A (tp = 5/50ns)
- Cable Discharge Event (CDE)
- Ultra-small package (1.0 x 0.6 x 0.4mm)
- Protects one I/O line
- Low capacitance: 0.8pF
- Low clamping voltage
- Solid-state silicon-avalanche technology
- AEC-Q100 Grade 1 qualified

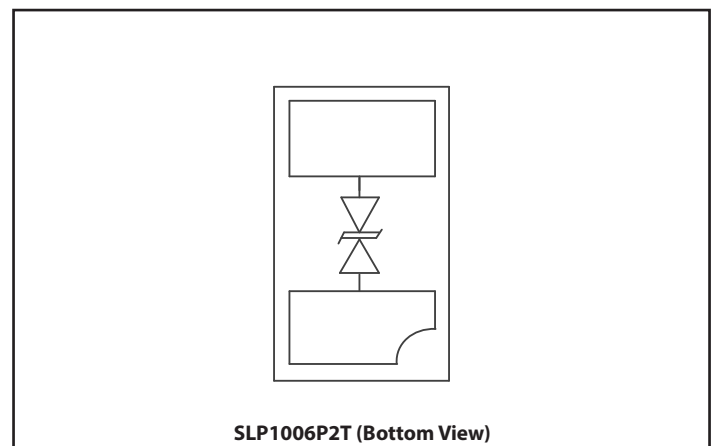
Mechanical Characteristics

- SLP1006P2T package
- Molding compound flammability rating: UL 94V-0
- Marking: Marking code + date code
- Packaging : Tape and Reel
- Lead Finish: NiPdAu
- Pb-Free, Halogen Free, RoHS/WEEE Compliant

Applications

- Cellular Handsets & Accessories
- Digital Visual Interface (DVI)
- FM Antenna
- MDDI Ports
- USB Ports
- PCI Express
- Serial ATA
- Automotive Applications

Schematic & Pin Configuration



Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PK}	80	W
Peak Pulse Current ($t_p = 8/20\mu s$)	I_{PP}	4	A
ESD per IEC 61000-4-2 (Air) ⁽¹⁾ ESD per IEC 61000-4-2 (Contact) ⁽¹⁾	V_{ESD}	± 20 ± 12	kV
Operating Temperature	T_J	-40 to +125	$^{\circ}C$
Storage Temperature	T_{STG}	-55 to +150	$^{\circ}C$

Electrical Characteristics (T=25 $^{\circ}C$ unless otherwise specified)

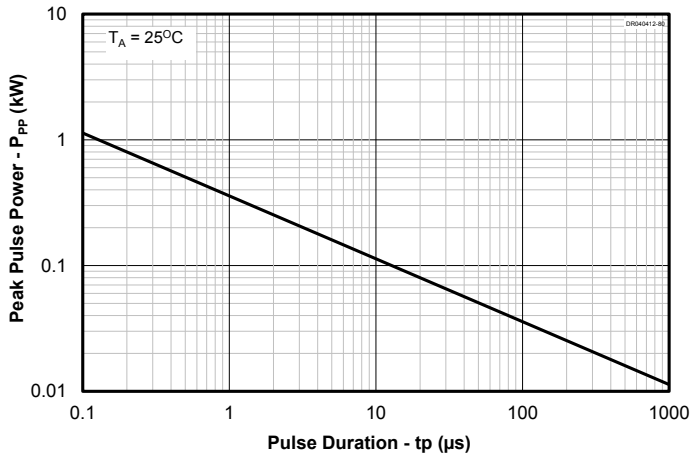
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units	
Reverse Stand-Off Voltage	V_{RWM}				5	V	
Reverse Breakdown Voltage	V_{BR}	$I_{BR} = 1 \text{ mA}$	6	9.3	11	V	
Reverse Leakage Current	I_R	$V_{RWM} = 5V, T = 25^{\circ}C$		0.010	0.100	μA	
		$V_{RWM} = 5V, T = 125^{\circ}C$		0.020	0.200		
Clamping Voltage	V_C	$t_p = 8/20\mu s$	$I_{PP} = 1A$			12	V
			$I_{PP} = 4A$			20	
Junction Capacitance	C_J	$V_R = 0V \text{ to } 5V, f = 1MHz, T = 25^{\circ}C$		0.50	0.80	pF	
		$V_R = 0V \text{ to } 5V, f = 1GHz, T = 125^{\circ}C$		0.85	1.5		

Notes

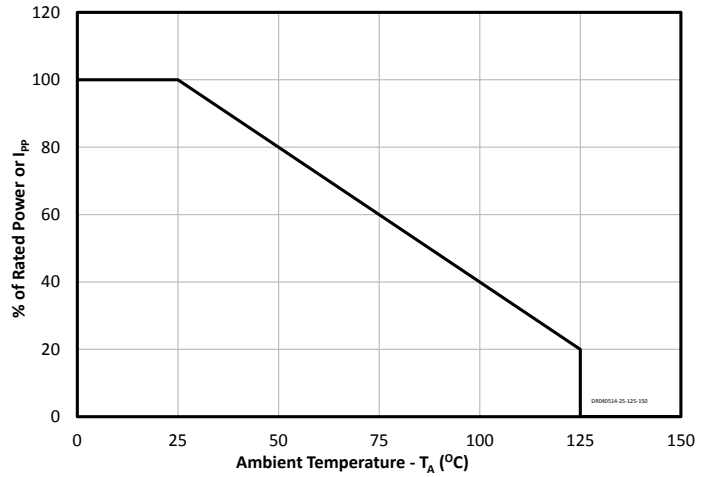
1) ESD gun return path connected to ESD ground plane.

Typical Characteristics

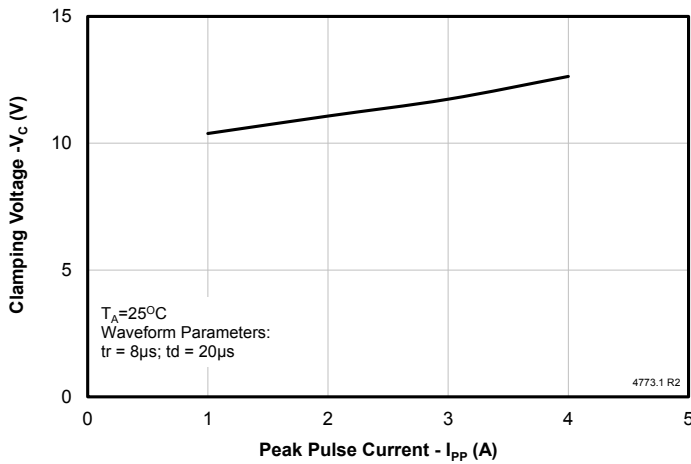
Non-Repetitive Peak Pulse Power vs. Pulse Time



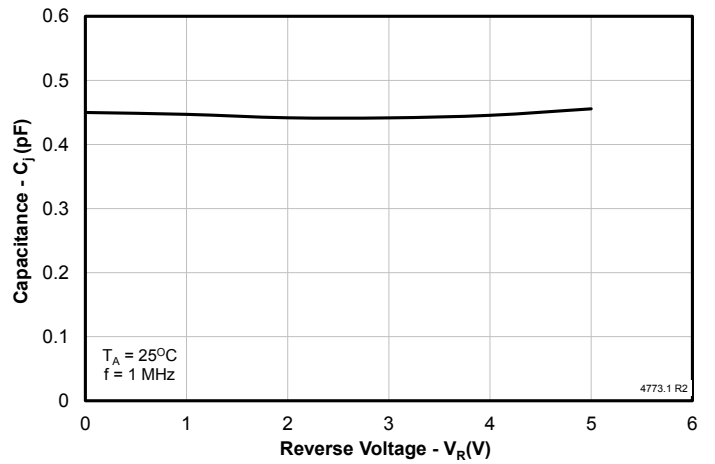
Power Derating Curve



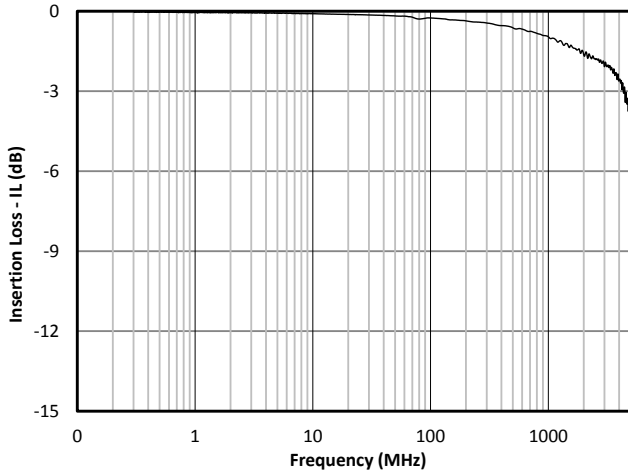
Clamping Voltage vs. Peak Pulse Current



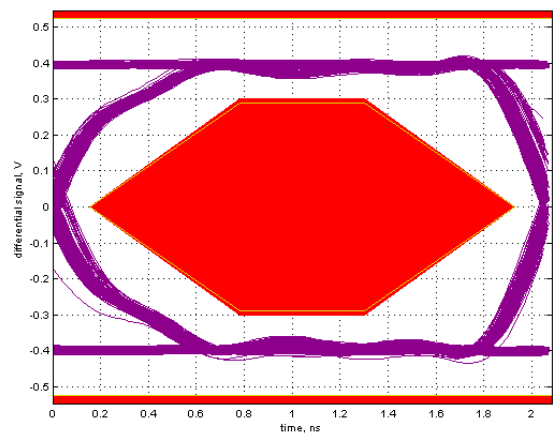
Junction Capacitance vs. Reverse Voltage



Insertion Loss (S21)

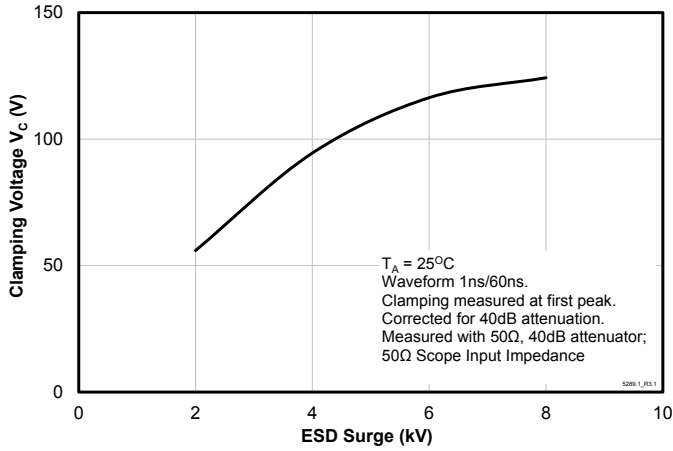


USB 2.0 Eye Pattern with RClamp0531TQ

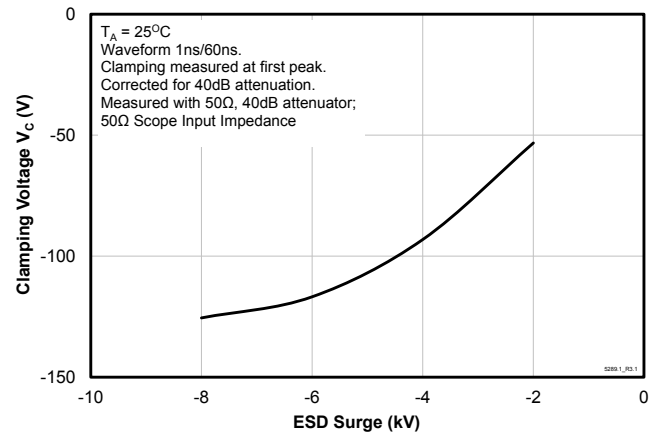


Typical Characteristics

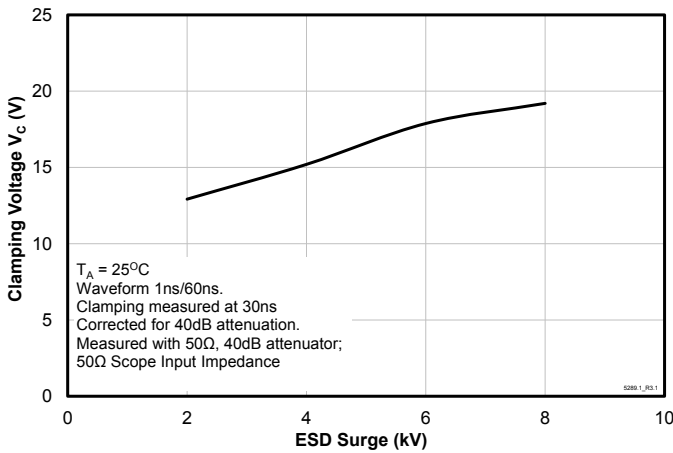
**ESD Clamping per IEC61000-4-2
Positive clamping voltage at first peak**



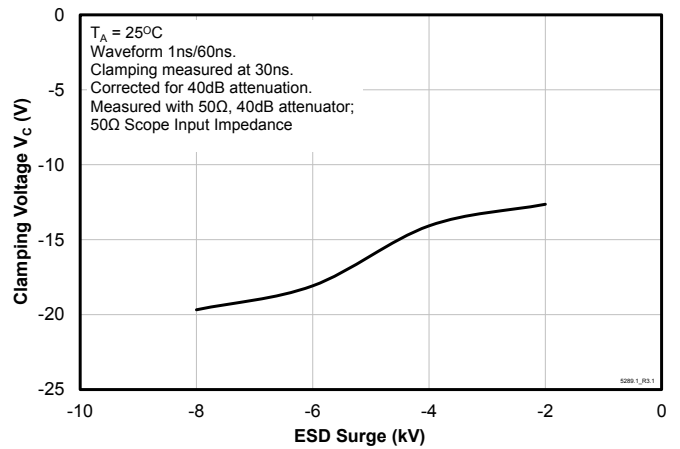
**ESD Clamping per IEC61000-4-2
Negative clamping voltage at first peak**



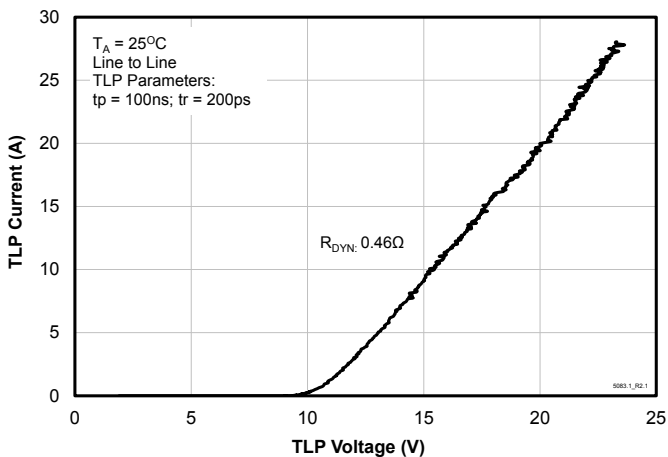
**ESD Clamping per IEC61000-4-2
Positive clamping voltage at 30ns**



**ESD Clamping per IEC61000-4-2
Negative clamping voltage at 30ns**

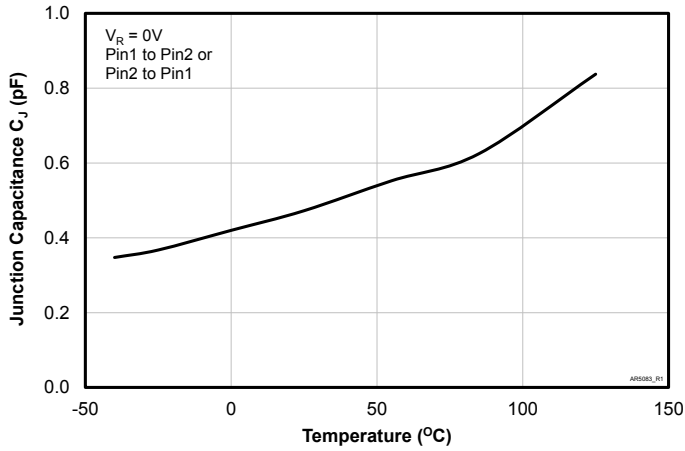


Typical TLP Characteristics

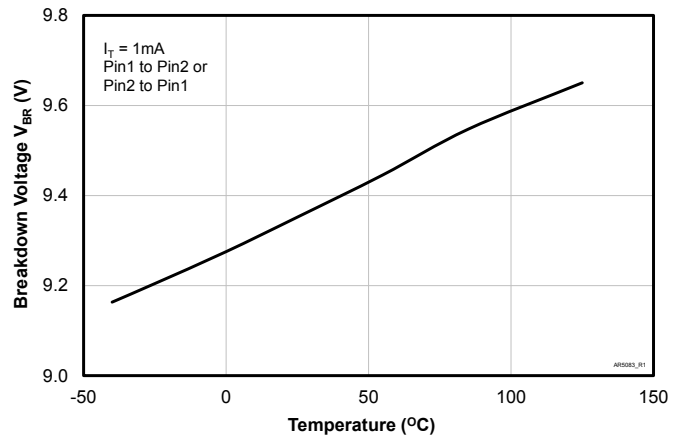


Typical Characteristics

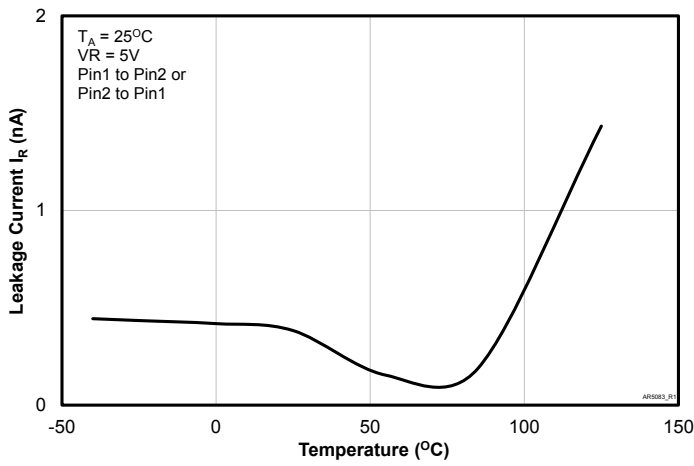
Typical Capacitance vs. Temperature



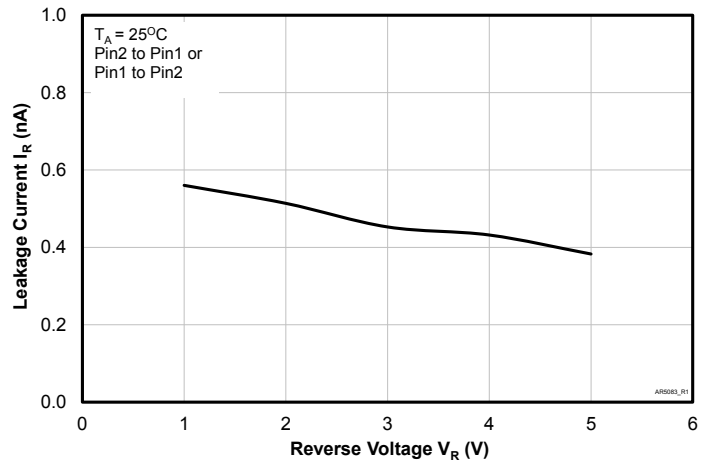
Typical Breakdown Voltage vs. Temperature



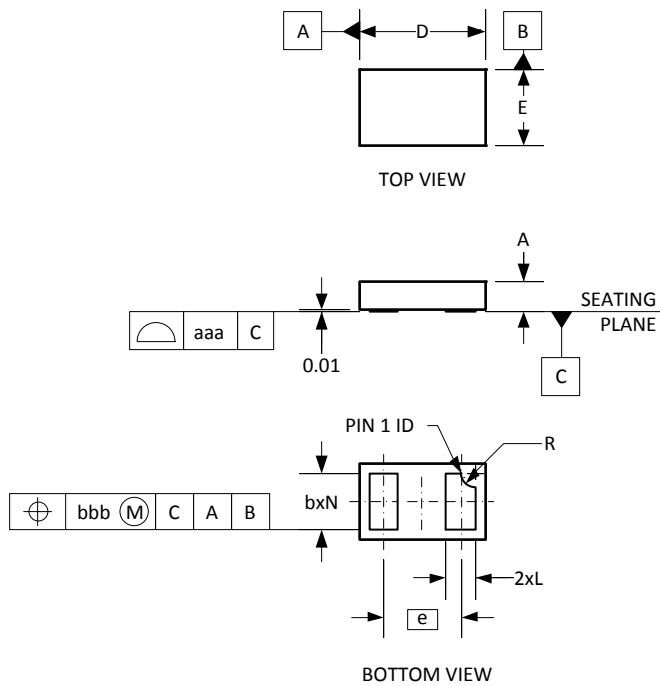
Typical Leakage Current vs. Temperature



Typical Leakage Current vs. Reverse Voltage



Outline Drawing - SLP1006P2T



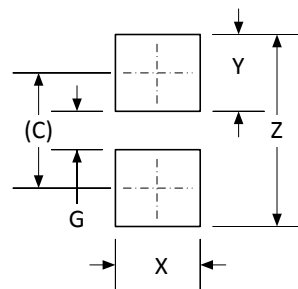
DIM	DIMENSIONS					
	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	.015	.016	.017	0.37	0.40	0.43
A1	.000	.001	.002	0.00	0.03	0.05
b	.018	.020	.022	0.45	0.50	0.55
D	.035	.039	.043	0.90	1.00	1.10
E	.020	.024	.028	0.50	0.60	0.70
e	.026 BSC			0.65 BSC		
L	.008	.010	.012	0.20	0.25	0.30
R	.002	.004	.006	0.05	0.10	0.15
N	2			2		
aaa	.003			0.08		
bbb	.004			0.10		

SLP1006P2T-2-R0

NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).

Land Pattern - SLP1006P2T



DIM	DIMENSIONS	
	INCHES	MILLIMETERS
C	(.033)	(0.85)
G	.012	0.30
X	.024	0.60
Y	.022	0.55
Z	.055	1.40

SLP1006P2T-3-R0

NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

